2SB937, 2SB937A

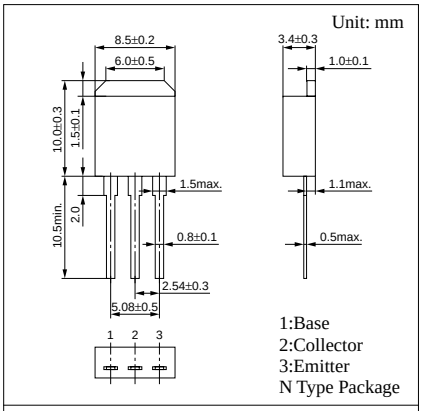
Silicon PNP epitaxial planar type Darlington

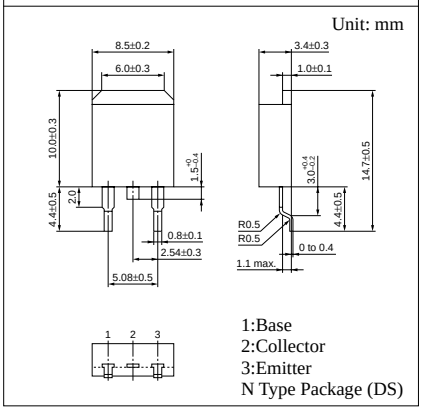
For power amplification and switching

Complementary to 2SD1260 and 2SD1260A

Features

- High foward current transfer ratio h_{FE}
- High-speed switching
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.





Absolute Maximum Ratings (T_C=25˚C)

Parameter		Symbol	Ratings	Unit
Collector to base voltage	2SB937	V_{CBO}	–60	V
	2SB937A		–80	
Collector to emitter voltage	2SB937	V_{CEO}	–60	V
	2SB937A		–80	
Emitter to base voltage		V_{EBO}	–5	V
Peak collector current		I_{CP}	–4	A
Collector current		I_C	–2	A
Collector power dissipation	T_C=25°C	P_C	35	W
	Ta=25°C		1.3	
Junction temperature		T_j	150	˚C
Storage temperature		T_{stg}	–55 to +150	˚C

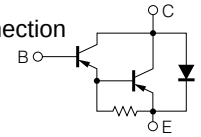
Electrical Characteristics (T_C=25˚C)

Parameter		Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	2SB937	I_{CBO}	V_{CB} = –60V, I_E = 0			–1	mA
	2SB937A		V_{CB} = –80V, I_E = 0			–1	
Collector cutoff current	2SB937	I_{CEO}	V_{CE} = –30V, I_B = 0			–2	mA
	2SB937A		V_{CE} = –40V, I_B = 0			–2	
Emitter cutoff current		I_{EBO}	V_{EB} = –5V, I_C = 0			–2	mA
Collector to emitter voltage	2SB937	V_{CEO}	I_C = –30mA, I_B = 0	–60			V
	2SB937A			–80			
Forward current transfer ratio		h_{FE1}	V_{CE} = –4V, I_C = –1A	1000			
		h_{FE2}*	V_{CE} = –4V, I_C = –2A	2000		10000	
Base to emitter voltage		V_{BE}	V_{CE} = –4V, I_C = –2A			–2.8	V
Collector to emitter saturation voltage		$V_{CE(sat)}$	I_C = –2A, I_B = –8mA			–2.5	V
Transition frequency		f_T	V_{CE} = –10V, I_C = – 0.5A, f = 1MHz		20		MHz
Turn-on time		t_{on}	I_C = –2A, I_{B1} = –8mA, I_{B2} = 8mA		0.4		µs
Storage time		t_{stg}			1.5		µs
Fall time		t_f			0.5		µs

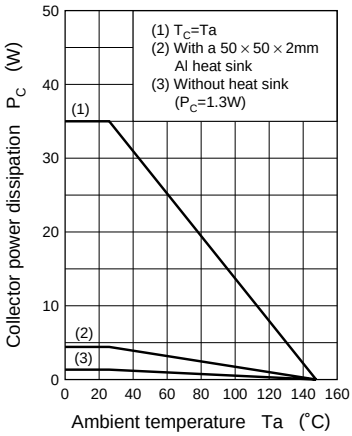
*h_{FE2} Rank classification

Rank	Q	P
h_{FE2}	2000 to 5000	4000 to 10000

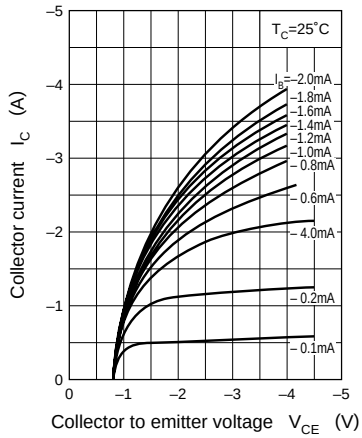
Internal Connection



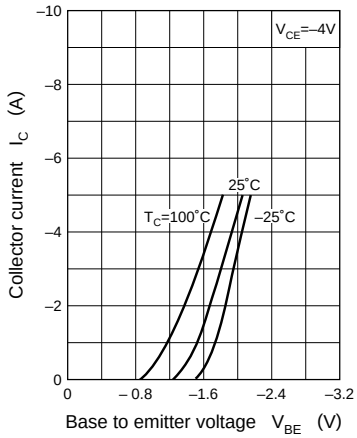
P_C — Ta



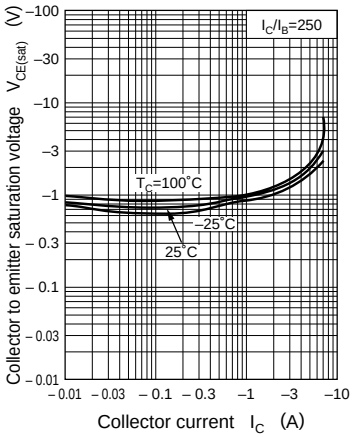
I_C — V_{CE}



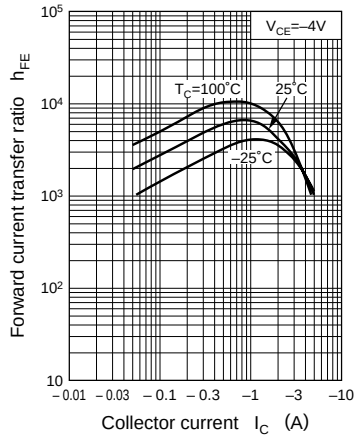
I_C — V_{BE}



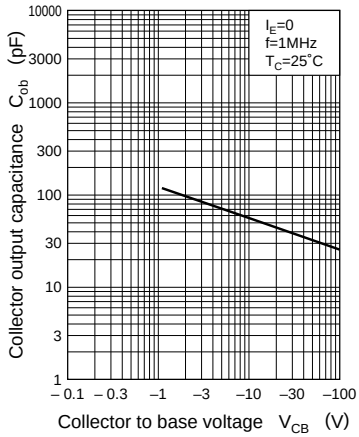
$V_{CE(sat)}$ — I_C



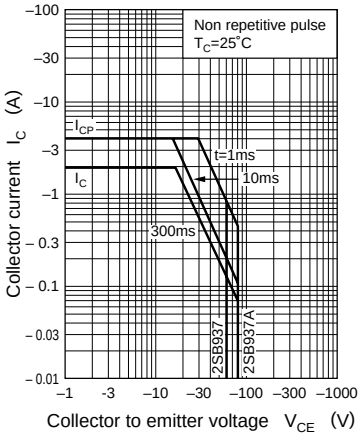
h_{FE} — I_C



C_{ob} — V_{CB}



Area of safe operation (ASO)



$R_{th(t)}$ — t